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## FAIRCHILD

SEMICONDUCTOR®

#### November 2013

FDB5800 — N-Channel Logic Level PowerTrench<sup>®</sup> MOSFET

# FDB5800

# N-Channel Logic Level PowerTrench<sup>®</sup> MOSFET 60 V, 80 A, 6 mΩ

#### Features

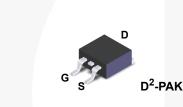
- $R_{DS(on)}$  = 4.6 m $\Omega$  (Typ.),  $V_{GS}$  = 10 V,  $I_D$  = 80 A
- High Performance Trench Technology for Extermly Low R<sub>DS(on)</sub>
- Low Gate Charge
- High Power and Current Handing Capability
- RoHs Compliant

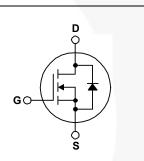
## Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

#### Applications

- Power tools
- Motor drives and Uninterruptible Power Supplies





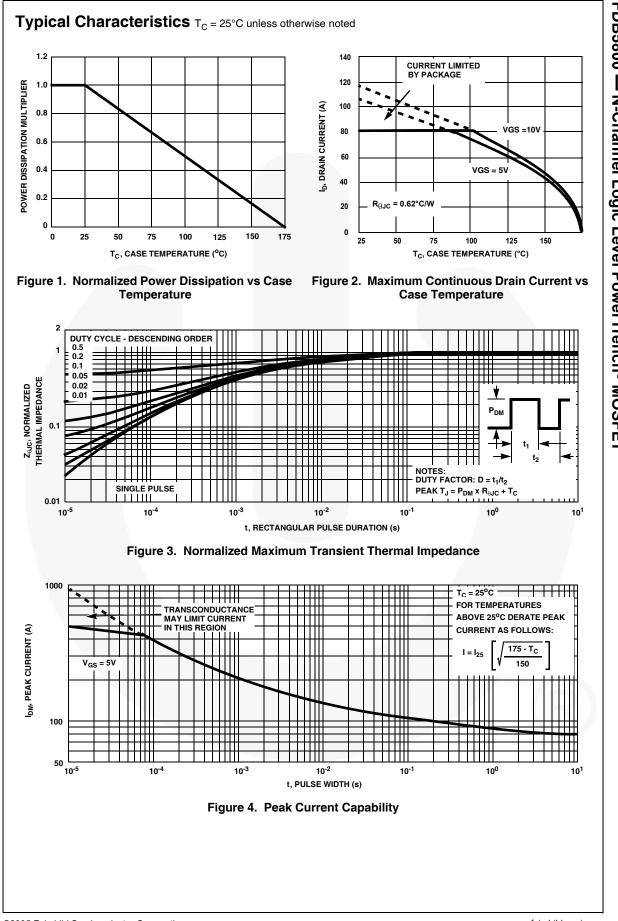
#### Absolute Maximum Ratings T<sub>c</sub> = 25°C unless otherwise noted.

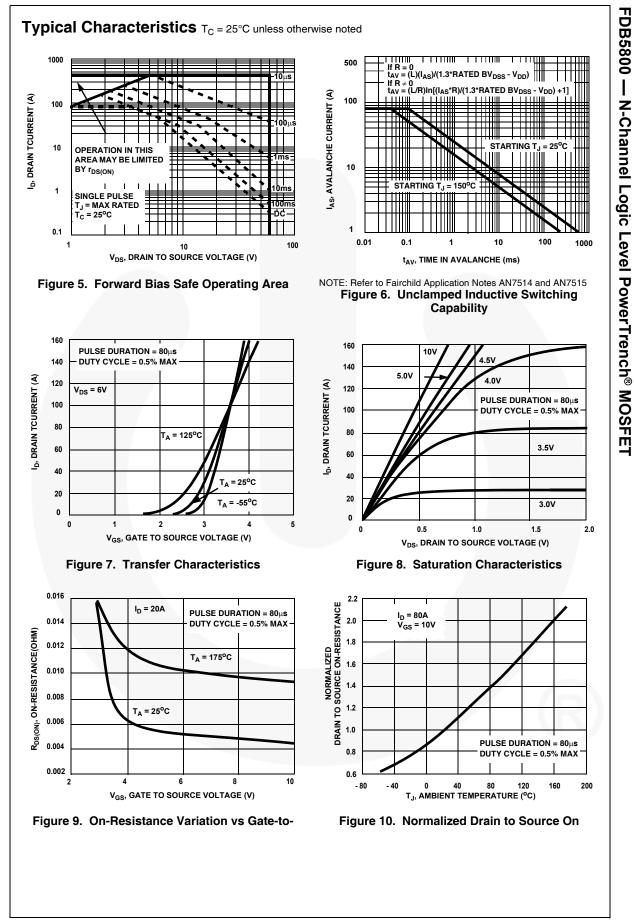
Symbol	Parameter		FDB5800	Unit
V <sub>DSS</sub>	Drain to Source Voltage		60	V
V <sub>GS</sub>	Gate to Source Voltage		±20	V
	Drain Current - Continuous (T <sub>C</sub> < 102 <sup>o</sup> C, V <sub>GS</sub> = 10 V)		80	А
I <sub>D</sub>	- Continuous ( $T_C < 90^{\circ}C$ , $V_{GS} = 5 V$ )		80	Α
	- Continuous ( $T_{amb}$ = 25°C, $V_{GS}$ = 10V, with $R_{\theta JA}$ = 43°C/W)		14	Α
	- Pulsed		Figure 4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy (	Note 1)	652	mJ
P <sub>D</sub>	- Power Dissipation		242	W
	- Derate above 25°C		1.61	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	- Operating and Storage Temperature		-55 to 175	°C

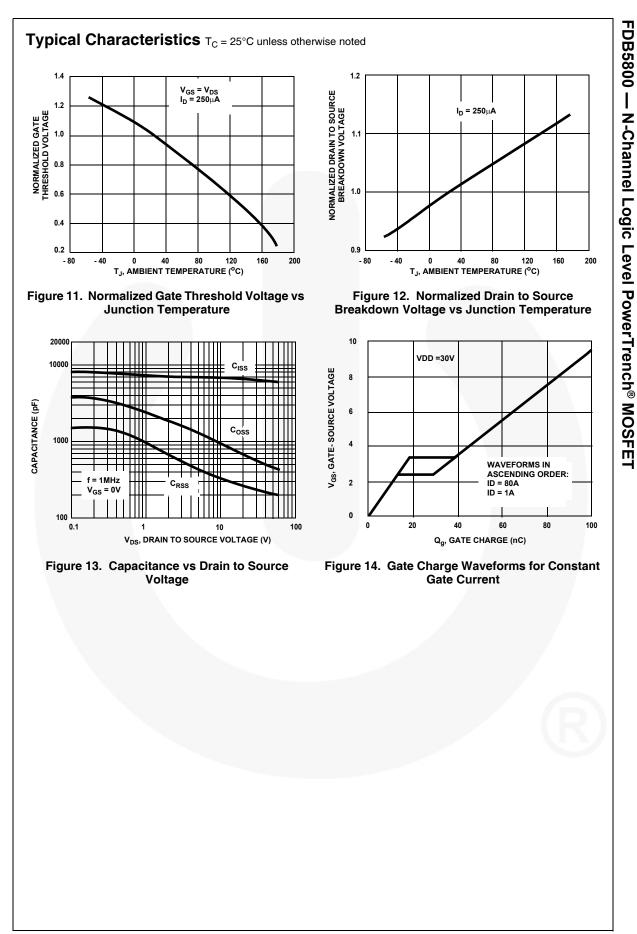
### **Thermal Characteristics**

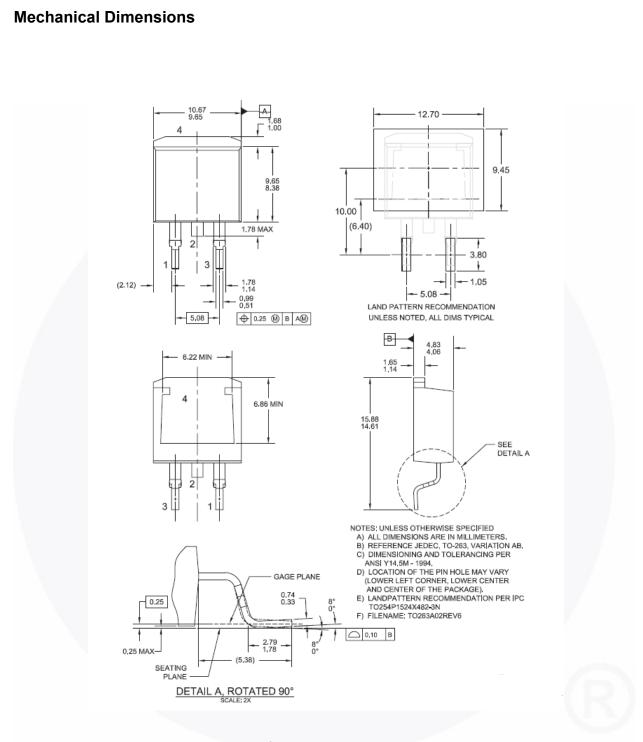
$R_{\theta JC}$	Thermal Resistance Junction to Case TO-263, Max.	0.62	°C/W
$R_{ hetaJA}$	Thermal Resistance Junction to Ambient TO-263, Max. (Note 2)	62.5	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance Junction to Ambient TO-263, 1in <sup>2</sup> copper pad area	43	°C/W

	Part Number Top Mark Pack		Packa	ge	Packing	Method	Reel	Size	Tape Wig	dth Qi	uantity
FDB5800 FDB5800					330		24 mm		800 units		
		1				1					
lectrica	al Chai	racteristics	T <sub>c</sub> = 25°C unles	s otherwise	noted.						
Symbol		Parameter			Test Co	nditions		Min.	Тур.	Max.	Unit
Off Chara	oteristio	<u> </u>									
	Drain to Source Breakdown Voltage							60	-	-	V
B <sub>VDSS</sub>	Zero Gate Voltage Drain Current Gate to Source Leakage Current		$I_D = 250 \ \mu A, V_{GS} = 0 \ V$ $V_{DS} = 48 \ V$			- 00	-	- 1	v		
I <sub>DSS</sub>			$V_{GS} = 0 V$ $T_{C} = 150^{\circ}C$			0°C	_	-	250	μA	
I <sub>GSS</sub>			$V_{CS} = -$	$V_{GS} = \pm 20 V$			-	-	±100	nA	
		-		- 63							
On Chara	cteristic	s								-	
V <sub>GS(TH)</sub>	Gate to S	Source Threshold \	/oltage		V <sub>DS</sub> , I <sub>D</sub> =			1.0	-	2.5	V
					A, V <sub>GS</sub> =			-	4.6	6.0	
					A, V <sub>GS</sub> =			-	5.8	7.2	-
r <sub>DS(ON)</sub>	Drain to	Source On Resista	ince		A, V <sub>GS</sub> =			-	5.5	7.0	mΩ
				I <sub>D</sub> = 80 T <sub>.1</sub> = 17	A, V <sub>GS</sub> = 75°C	= 10 V,		- 10 12.6			
Dynamic	Charact	eristics							<u> </u>		
C <sub>ISS</sub>	-	pacitance	_					-	6625	-	pF
C <sub>OSS</sub>		apacitance			15 V, V <sub>G</sub>	<sub>3</sub> = 0 V,	ŀ	-	628	-	pF
C <sub>RSS</sub>	-	Transfer Capacita	nce	f = 1 M	Hz		ŀ	-	262	-	pF
R <sub>G</sub>	Gate Res			$V_{CS} = 0$	0.5 V, f =	1 MHz		-	1.4	-	Ω
Q <sub>g(TOT)</sub>	Total Ga	te Charge at 10V		$V_{GS} = 0 V \text{ to } 10 V$			-	104	135	nC	
$Q_{g(5)}$		te Charge at 5V	_	$V_{cc} = 0 V to 5 V$			ŀ	-	55	72	nC
Q <sub>g(TH)</sub>		d Gate Charge	_	$V_{GS} = 0$	0 V to 1 \	V <sub>DD</sub> = 30 V I <sub>D</sub> = 80 A		-	6.0	-	nC
Q <sub>gs</sub>		Source Gate Charg	e	00		l <sub>D</sub> = 80 الـــــ ا <sub>a</sub> = 1.0	A	-	18.4	-	nC
Q <sub>gs2</sub>		arge Threshold to I				l <sub>g</sub> = 1.0	IIIA -	-	12.5	-	nC
Q <sub>gd</sub>	Gate to I	Drain "Miller" Charg	je	_			F	-	20.1	-	nC
<b>J</b> .											
Switching	g Charao	cteristics (V <sub>GS</sub>	= 5V)								
t <sub>ON</sub>	Turn-On	Time						-	-	62.1	ns
t <sub>d(ON)</sub>	Turn-On	Delay Time		V <sub>DD</sub> = 30 V, I <sub>D</sub> = 80 A			Γ	-	20.3	-	ns
	Rise Tim	е						-	22.0	-	ns
		urn-Off Delay Time		$V_{GS}$ = 5 V, $R_{GS}$ = 2 $\Omega$				-	27.1	-	ns
t <sub>r</sub>	Turn-Off	Delay Time		00					12.1		
t <sub>r</sub> t <sub>d(OFF)</sub>	Turn-Off Fall Time			00				-	12.1	-	ns
t <sub>r</sub> t <sub>d(OFF)</sub> t <sub>f</sub>	-	9						-	-	- 59.0	ns ns
t <sub>r</sub> t <sub>d(OFF)</sub> t <sub>f</sub> t <sub>OFF</sub>	Fall Time Turn-Off	9	stics					-	-	59.0	
t <sub>r</sub> t <sub>d(OFF)</sub> t <sub>f</sub> t <sub>OFF</sub> Drain-Sou	Fall Time Turn-Off	e Time de Characteri		I <sub>SD</sub> = 8	0 A			-	-	- 59.0 1.25	
t <sub>r</sub> t <sub>d(OFF)</sub> t <sub>f</sub> t <sub>OFF</sub>	Fall Time Turn-Off	Time						-	-		ns
t <sub>r</sub> t <sub>d(OFF)</sub> t <sub>f</sub> t <sub>OFF</sub> Drain-Sou	Fall Time Turn-Off urce Dio Source to	e Time de Characteri		<sub>SD</sub> = 8   <sub>SD</sub> = 4	0 A	/dt = 100 A	¥μs	-	-	1.25	ns V









#### Figure 15. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount

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